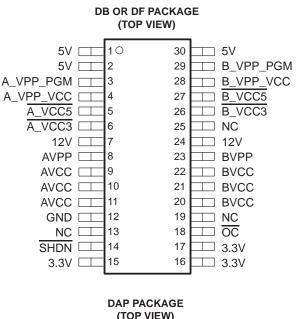
- Fully Integrated V_{CC} and V_{pp} Switching for Dual-Slot PC Card[™] Interface
- Compatible with Controllers From Cirrus, Ricoh, O₂Micro, Intel, and Texas Instruments
- 3.3-V Low-Voltage Mode
- Meets PC Card Standards
- 12-V Supply Can Be Disabled Except During 12-V Flash Programming
- Short Circuit and Thermal Protection
- 30-Pin SSOP (DB) and 32-Pin TSSOP (DAP)
- Compatible With 3.3-V, 5-V and 12-V PC Cards
- Low r_{DS(on)} (140-mΩ 5-V V_{CC} Switch; 110-mΩ 3.3-V V_{CC} Switch)
- Break-Before-Make Switching

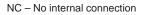
description

The TPS2205 PC Card power-interface switch provides an integrated power-management solution for two PC Cards. All of the discrete power MOSFETs, a logic section, current limiting, and thermal protection for PC Card control are combined on a single integrated circuit (IC), using the Texas Instruments LinBiCMOS[™] process. The circuit allows the distribution of 3.3-V, 5-V, and/or 12-V card power, and is compatible with many PCMCIA controllers. The current-limiting feature eliminates the need for fuses, which reduces component count and improves reliability.

The TPS2205 is backward compatible with the TPS2201, except that there is no V_{DD} connection. Bias current is derived from either the 3.3-V input pin or the 5-V input pin. The TPS2205 also eliminates the APWR_GOOD and BPWR_GOOD pins of the TPS2201.



	(TOP VIEV	W)
5V 5V NC A_VPP_PGM A_VCC5 A_VCC3 AVCC AVCC AVCC AVCC AVCC SHDN SHDN NC 3.3V	1 O 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16	32 5V 31 NC 30 B_VPP_PGM 29 B_VCC5 27 NC 26 B_VCC3 25 12V 24 BVPP 23 BVCC 22 BVCC 21 BVCC 20 OC 19 NC 18 3.3V 17 3.3V



The TPS2205 features a 3.3-V low-voltage mode that allows for 3.3-V switching without the need for 5 V. This facilitates low-power system designs such as sleep mode and pager mode where only 3.3 V is available.

ł

End equipment for the TPS2205 includes notebook computers, desktop computers, personal digital assistants (PDAs), digital cameras, and bar-code scanners.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinBiCMOS is a trademark of Texas Instruments Incorporated. PC Card is a trademark of PCMCIA (Personal Computer Memory Card International Association).

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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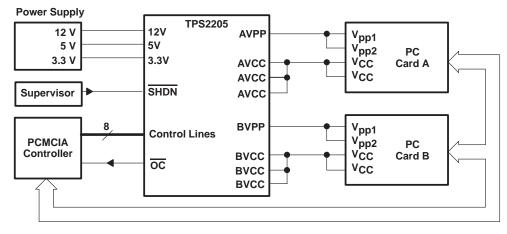
TPS2205 DUAL-SLOT PC CARD POWER-INTERFACE SWITCH FOR PARALLEL PCMCIA CONTROLLERS

SLVS128D OCTOBER	1995 - REVISED	JUNE 1998

AVAILABLE OPTIONS							
	P	ACKAGED DEVICES		CHIP FORM			
ТА	PLASTIC SMALL OUTLINE (DB)	PLASTIC SMALL OUTLINE (DF)	TSSOP (DAP)	(Y)			
-40°C to 85°C	TPS2205IDBLE	TPS2205IDFLE	TPS2205IDAPR	TPS2205Y			

The DB package and the DF package are only available left-end taped and reeled (indicated by the LE suffix on the device type; e.g., TPS2205IDBLE). The DAP package is only available taped and reeled (indicated by the R suffix on the device type; e.g., TPS2205IDAPR).

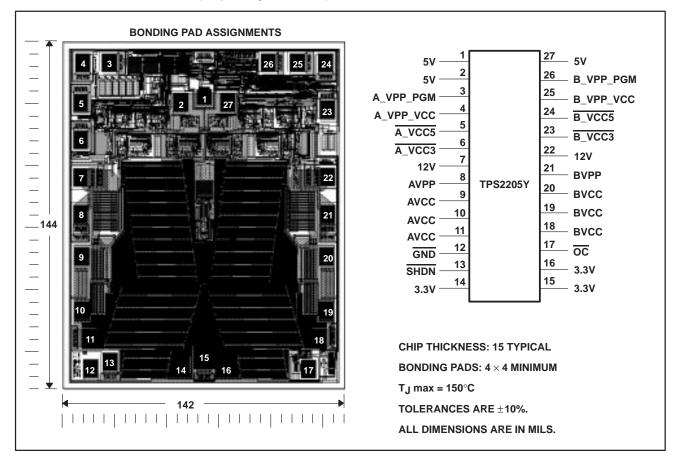
typical PC card power-distribution application





TPS2205Y chip information

This chip, when properly assembled, displays characteristics similar to those of the TPS2205. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. The chips may be mounted with conductive epoxy or a gold-silicon preform.





Terminal Functions

TERMINAL						
NAME NO.		NO.		NO.		DESCRIPTION
NAME	DB, DF	DAP				
A_VCC3	6	7	I	Logic input that controls voltage on AVCC (see TPS2205 Control-Logic table)		
A_VCC5	5	6	I	Logic input that controls voltage on AVCC (see TPS2205 Control-Logic table)		
A_VPP_PGM	3	4	I	Logic input that controls voltage on AVPP (see TPS2205 Control-Logic table)		
A_VPP_VCC	4	5	I	Logic input that controls voltage on AVPP (see TPS2205 Control-Logic table)		
AVCC	9, 10, 11	10, 11, 12	0	Switched output that delivers 0 V, 3.3 V, 5 V, or high impedance		
AVPP	8	9	0	Switched output that delivers 0 V, 3.3 V, 5 V, 12 V, or high impedance		
B_VCC3	26	26	I	Logic input that controls voltage on BVCC (see TPS2205 Control-Logic table)		
B_VCC5	27	28	I	Logic input that controls voltage on BVCC (see TPS2205 Control-Logic table)		
B_VPP_PGM	29	30	I	Logic input that controls voltage on BVPP (see TPS2205 Control-Logic table)		
B_VPP_VCC	28	29	I	Logic input that controls voltage on BVPP (see TPS2205 Control-Logic table)		
BVCC	20, 21, 22	21, 22, 23	0	Switched output that delivers 0 V, 3.3 V, 5 V, or high impedance		
BVPP	23	24	0	Switched output that delivers 0 V, 3.3 V, 5 V, 12 V, or high impedance		
SHDN	14	14	I	Logic input that shuts down the TPS2205 and set all power outputs to high-impedance state		
<u>oc</u>	18	20	0	Logic-level overcurrent reporting output that goes low when an overcurrent condition exists		
GND	12	13		Ground		
3.3V	15, 16, 17	16, 17, 18	I	3.3-V V _{CC} in for card power		
5V	1, 2, 30	1, 2, 32	Ι	5-V V _{CC} in for card power		
12V	7, 24	8, 25	I	12-V VPP in for card power		
NC	13, 19, 25	3, 15, 19, 27, 31	I	No internal connection		

absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Input voltage range for card power: V _{I(5V)} V _{I(3.3V)}	
V _{I(12V)}	
Logic input voltage	0.3 V to 7 V
Continuous total power dissipation	. See Dissipation Rating Table
Output current (each card): I _{O(xVCC)}	Internally limited
I _{O(xVPP)}	Internally limited
Operating virtual junction temperature range, T _J	40°C to 150°C
Operating free-air temperature range, T _A	–40°C to 85°C
Storage temperature range, T _{stg}	–55°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



DISSIPATION RATING TABLE									
PACKAGE		$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING				
DB		1024 mW	8.2 mW/°C	655 mW	532 mW				
DF		1158 mW	9.26 mW/°C	741 mW	602 mW				
DAP	No backplane	1625 mW	13 mW/°C	1040 mW	845 mW				
DAP	Backplane§	6044 mW	48.36 mW/°C	3869 mW	3143 mW				

[‡]These devices are mounted on an FR4 board with no special thermal considerations.

2-oz backplane with 2-oz traces; 5.2-mm \times 11-mm thermal pad with 6-mil solder; 0.18-mm diameter vias in a 3 \times 6 array.

recommended operating conditions

		MIN	MAX	UNIT
Input voltage range, V _I Output current	VI(5V)	0	5.25	V
	VI(3.3V)	0	5.25	V
	VI(12V)	0	13.5	V
Output current	I _{O(xVCC)} at 25°C		1	А
	I _{O(xVPP)} at 25°C		150	mA
Operating virtual junction temperature, TJ		-40	125	°C

electrical characteristics, $T_A = 25^{\circ}C$, $V_{I(5V)} = 5 V$ (unless otherwise noted)

dc characteristics

	DADAMETE		TEST CONDITIONS	TPS2205			
		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
		5 V to xVCC			103	140 110 180 6 6 1 1 0.8 0.8 0.8 10 50	
		3.3 V to xVCC	$V_{I(5V)} = 5 V,$ $V_{I(3.3 V)} = 3.3 V$		69	110	mΩ
	Switch resistances [†]	3.3 V to xVCC	$V_{I(5V)} = 0,$ $V_{I(3.3V)} = 3.3 V$		96	180	
	Switch resistances	5 V to xVPP				6	
		3.3 V to xVPP				6	Ω
		12 V to xVPP				1	
VO(xVPP)	Clamp low voltage		I _{pp} at 10 mA			0.8	V
VO(xVCC)	Clamp low voltage		I _{CC} at 10 mA			0.8	V
	Leakage current	I _{pp} high-impedance state	$T_A = 25^{\circ}C$		1	10	
1			T _A = 85°C			50	
likg		ICC high-impedance	$T_A = 25^{\circ}C$		1	10	μA
		state	T _A = 85°C			50	
	Input current	V _{I(5V)} = 5 V	$V_{O(AVCC)} = V_{O(BVCC)} = 5 V,$ $V_{O(AVPP)} = V_{O(BVPP)} = 12 V$		117	150	A
lı		V _{I(5V)} = 0, V _{I(3.3V)} = 3.3 V	$V_{O(AVCC)} = V_{O(BVCC)} = 3.3 V,$ $V_{O(AVPP)} = V_{O(BVPP)} = 0$		131	150	μA
		Shutdown mode	$V_{O(BVCC)} = V_{O(AVCC)}$ = $V_{O(AVPP)} = V_{O(BVPP)} = Hi-Z$			1	μΑ
	Short-circuit	I _{O(xVCC)}	T _J = 85°C,	1		2.2	А
los	output-current limit	IO(xVPP)	Output powered up into a short to GND	120		400	mA

[†] Pulse-testing techniques are used to maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.



electrical characteristics, $T_A = 25^{\circ}C$, $V_{I(5V)} = 5 V$ (unless otherwise noted)

logic section

PARAMETER	TEST CONDITIONS	TPS2205	UNIT	
PARAIMETER	TEST CONDITIONS	MIN	MAX	UNIT
Logic input current			1	μA
Logic input high level		2		V
Logic input low level			0.8	V
	$V_{I(5V)} = 5 V$, $I_{O} = 1mA$	V _{I(5V)} -0.4		
Logic output high level	V _{I(5V)} = 0 V, I _O = 1mA, V _{I(3.3V)} = 3.3 V	V _{I(3.3V)} -0.4		V
Logic output low level	I _O = 1mA		0.4	V

switching characteristics^{†‡}

PARAMETER			TEST CONDITIONS			TPS2205		
	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
+	Output rise time	VO(xVCC)			1.2			
tr	Output lise time	VO(xVPP)			5		ms	
+-	Output fall time	VO(xVCC)			10		1115	
tf		V _O (xVPP)		14				
		VI(x_VPP_PGM) to VO(xVPP)	ton		4.4		ms	
			toff		18		ms	
			ton		6.5		ms	
	Propagation delay (see Figure 1)	$V_{I(x_VCC5)}$ to xVCC (3.3 V), $V_{I(5V)} = 5$ V	toff		20		ms	
^t pd	Fropagation delay (see Figure 1)		ton		5.7		ms	
		$V_{I}(x_{VCC5})$ to xVCC (5 V)	toff		25		ms	
			ton		6.6		ms	
		$V_{I}(\overline{x_VCC5})$ to xVCC (3.3 V), $V_{I}(5V) = 0$	toff		21		ms	

[†] Refer to Parameter Measurement Information

[‡] Switching Characteristics are with C_L = 150 μ F.



electrical characteristics, $T_A = 25^{\circ}C$, $V_{I(5V)} = 5 V$ (unless otherwise noted)

dc characteristics

	DADAME	TED	TEST CO	NDITIONS	TF	PS22051	′	UNIT
PARAMETER		TEST CO	NUTIONS	MIN	TYP	MAX	UNIT	
		5 V to xVCC				103		
		3.3 V to xVCC	$V_{I(5V)} = 5 V,$	V _{I(3.3 V)} = 3.3 V		69		mΩ
	8	3.3 V to xVCC	$V_{I(5V)} = 0,$	V _{I(3.3V)} = 3.3 V		96		
	Switch resistances§	5 V to xVPP				4.74		
		3.3 V to xVPP				4.74		Ω
		12 V to xVPP				0.724		
VO(xVPP)	Clamp low voltage		I _{pp} at 10 mA			0.275		V
V _{O(xVCC)}	Clamp low voltage		I _{CC} at 10 mA			0.275		V
		Ipp High-impedance state	T _A = 25°C			1		۵
likg	Leakage current	ICC High-impedance state	T _A = 25°C			1		μA
	Input current	V _{I(5V)} = 5 V	VO(AVCC) = VO(VO(AVPP) = VO(I	BVCC) = 5 V, BVPP) = 12 V		117		
lı		$V_{I(5V)} = 0,$ $V_{I(3.3V)} = 3.3 V$	V _{O(AVCC)} = V _{O(} V _{O(AVPP)} = V _{O(}	BVCC) = 3.3 V, BVPP) = 0		131		μA

§ Pulse-testing techniques are used to maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

switching characteristics^{†‡}

PARAMETER		TEST CONDITIONS		TPS2205Y			UNIT
	FARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
+	Output rise time	V _{O(xVCC)}			1.2		
tr	Output lise time	V _{O(xVPP)}			5		me
+,	Output fall time	VO(xVCC) VO(xVPP) VI(x, V/PP, PGM) to VO(xV/PP)		10		ms	
tf					14		
		VI(x_VPP_PGM) to VO(xVPP)	ton		4.4		ms
			toff		18		ms
			ton		6.5		ms
l	Propagation delay (see Figure 1)	$V_{I}(x_VCC5)$ to xVCC (3.3 V), $V_{I}(5V) = 5$ V	toff		20		ms
^t pd	Flopagation delay (see Figure 1)		ton		5.7		ms
		VI(x_VCC5) to xVCC (5 V)	toff		25		ms
			ton		6.6		ms
		$V_{I}(x_VCC5)$ to xVCC (3.3 V), $V_{I}(5V) = 0$	toff		21		ms

[†] Refer to Parameter Measurement Information

 \ddagger Switching Characteristics are with CL = 150 $\mu\text{F}.$



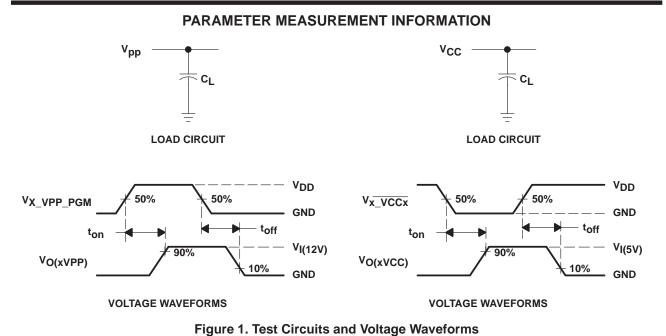
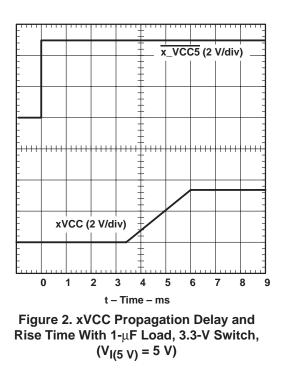


Table of Timing Diagrams

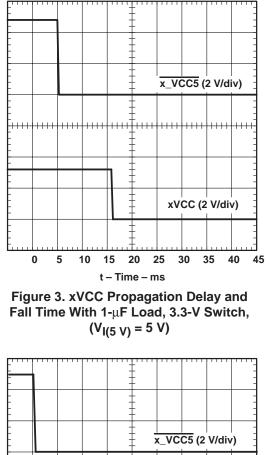
	FIGURE
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xVPP Propagation Delay and Fall Time With 150- μ F Load, 12-V Switch	17





0





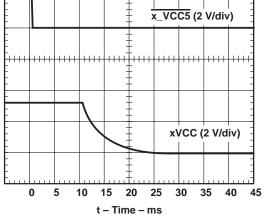
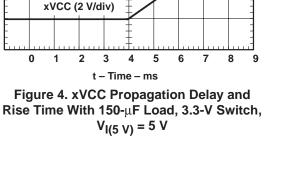


Figure 5. xVCC Propagation Delay and Fall Time With 150-µF Load, 3.3-V Switch, $V_{I(5 V)} = 5 V$

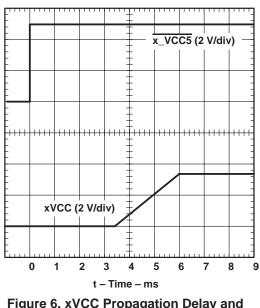


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x_VCC5 (2 V/div)

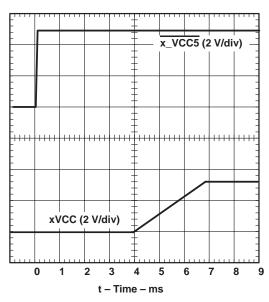
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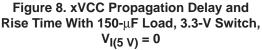
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PARAMETER MEASUREMENT INFORMATION

Figure 6. xVCC Propagation Delay and Rise Time With 1- μ F Load, 3.3-V Switch, V_{I(5 V)} = 0





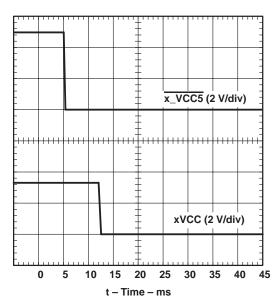
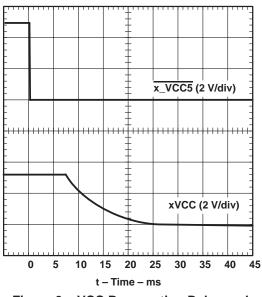
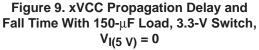
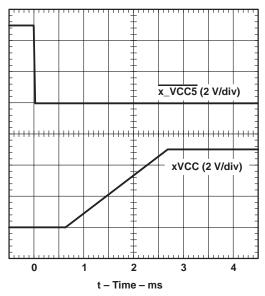


Figure 7. xVCC Propagation Delay and Fall Time With 1- μ F Load, 3.3-V Switch, V_{I(5 V)} = 0









PARAMETER MEASUREMENT INFORMATION

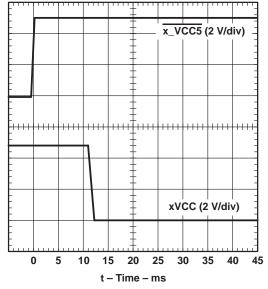


Figure 10. xVCC Propagation Delay and Rise Time With 1-μF Load, 5-V Switch

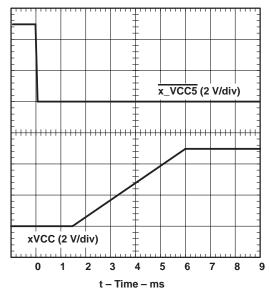


Figure 12. xVCC Propagation Delay and Rise Time With 150- μ F Load, 5-V Switch

Figure 11. xVCC Propagation Delay and Fall Time With 1- μ F Load, 5-V Switch

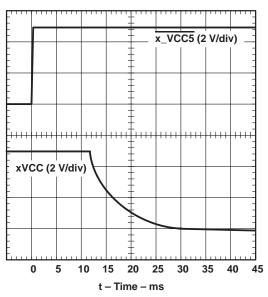
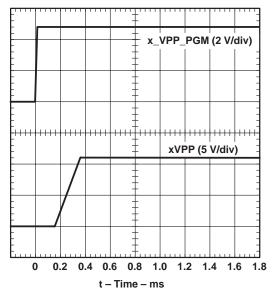


Figure 13. xVCC Propagation Delay and Fall Time With 150- μF Load, 5-V Switch





PARAMETER MEASUREMENT INFORMATION

Figure 14. xVPP Propagation Delay and Rise Time With 1- μ F Load, 12-V Switch

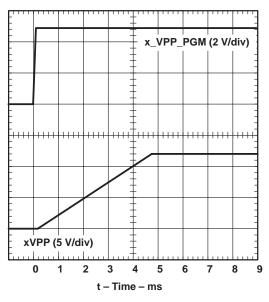


Figure 16. xVPP Propagation Delay and Rise Time With 150- μ F Load, 12-V Switch

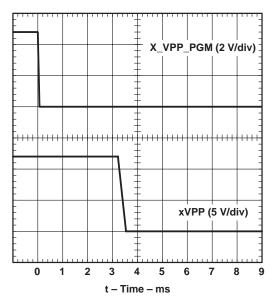


Figure 15. xVPP Propagation Delay and Fall Time With 1- μ F Load, 12-V Switch

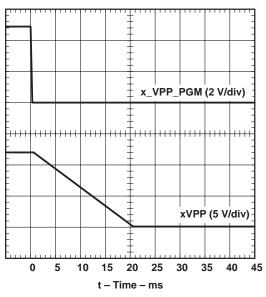


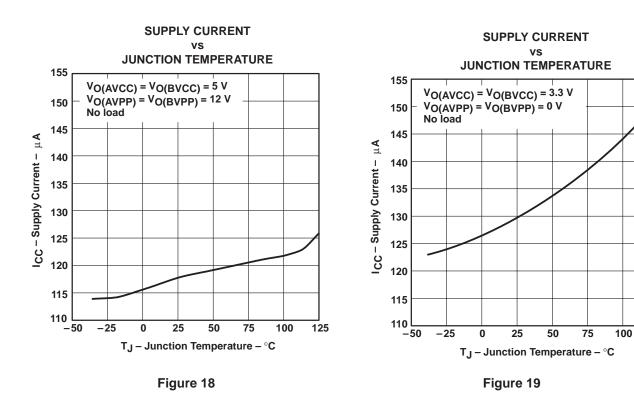
Figure 17. xVPP Propagation Delay and Fall Time With 150-μF Load, 12-V Switch



TYPICAL CHARACTERISTICS

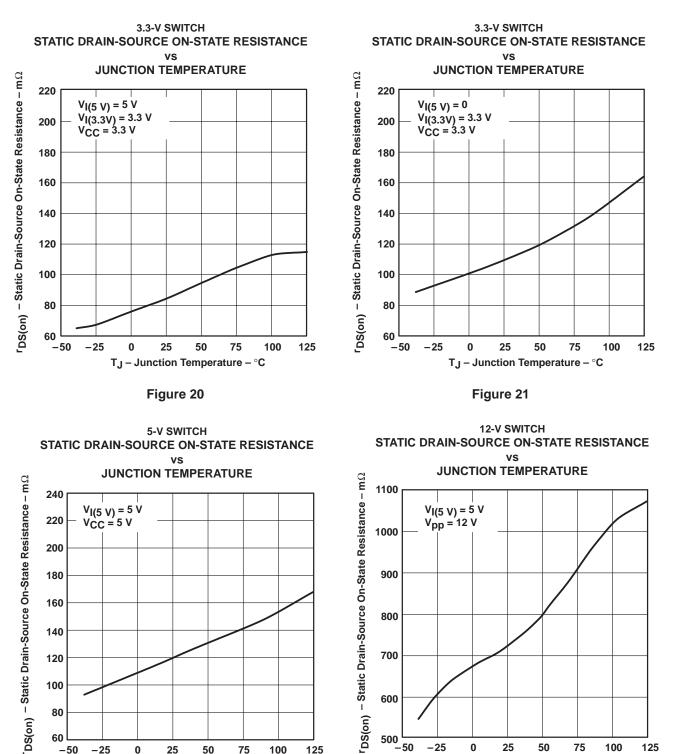
Table of Graphs

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IDD	Supply current, VI(5V) = 0, VI(12V) =0, VO(AVCC) = VO(BVCC) = 3.3 V	vs Junction temperature	19
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^r DS(on)	Static drain-source on-state resistance, 3.3-V switch, $V_{I(5V)} = 0$	vs Junction temperature	21
^r DS(on)	Static drain-source on-state resistance, 5-V switch	vs Junction temperature	22
^r DS(on)	Static drain-source on-state resistance, 12-V switch	vs Junction temperature	23
VO(xVCC)	Output voltage, 5-V switch	vs Output current	24
VO(xVCC)	Output voltage, 3.3-V switch	vs Output current	25
VO(xVCC)	Output voltage, 3.3-V switch, VI(5V) = 0	vs Output current	26
V _{O(xVPP)}	Output voltage, 12-V V _{pp} switch	vs Output current	27
IOS(xVCC)	Short-circuit current, 5-V switch	vs Junction temperature	28
IOS(xVCC)	Short-circuit current, 3.3-V switch	vs Junction temperature	29
IOS(xVPP)	Short-circuit current, 12-V switch	vs Junction temperature	30





125



TYPICAL CHARACTERISTICS



-50

-25

Figure 23

T_J – Junction Temperature – °C

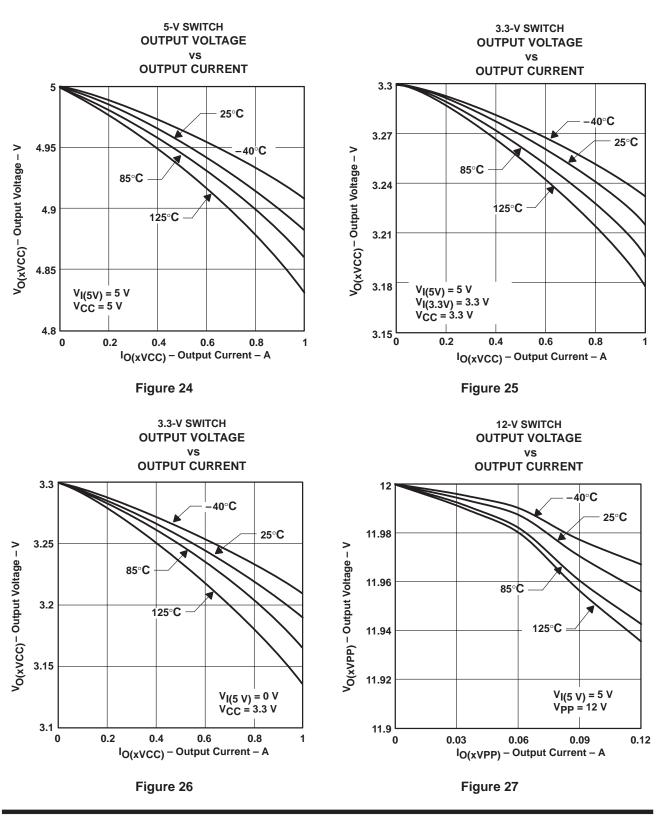
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-25

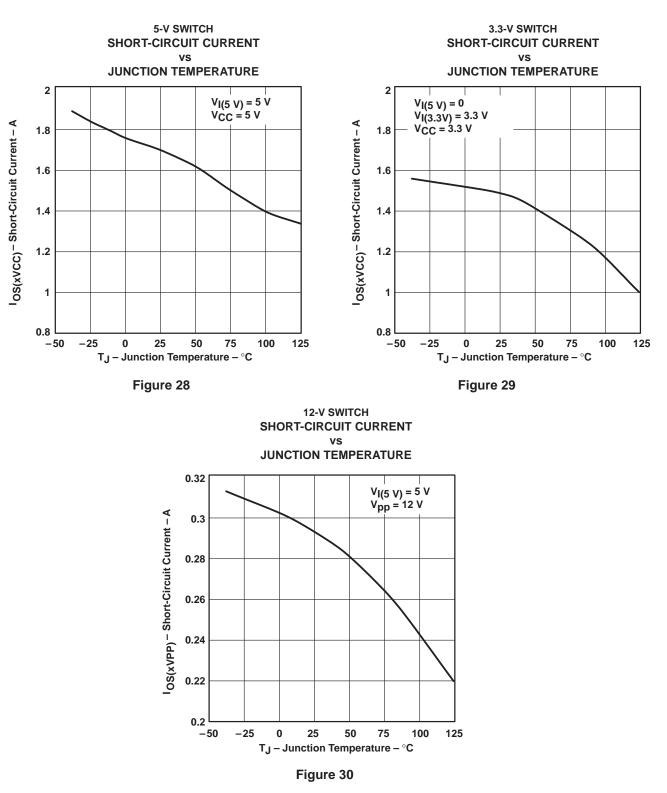
Figure 22

T_J – Junction Temperature – °C

TYPICAL CHARACTERISTICS







TYPICAL CHARACTERISTICS



APPLICATION INFORMATION

overview

PC Cards were initially introduced as a means to add EEPROM (flash memory) to portable computers with limited on-board memory. The idea of add-in cards quickly took hold; modems, wireless LANs, global positioning satellite system (GPS), multimedia, and hard-disk versions were soon available. As the number of PC Card applications grew, the engineering community quickly recognized the need for a standard to ensure compatibility across platforms. To this end, the PCMCIA was established, comprised of members from leading computer, software, PC Card, and semiconductor manufacturers. One key goal was to realize the "plug-and-play" concept. Cards and hosts from different vendors should be compatible — able to communicate with one another transparently.

PC Card power specification

System compatibility also means power compatibility. The most current set of specifications (PC Card Standard) set forth by the PCMCIA committee states that power is to be transferred between the host and the card through eight of 68 terminals of the PC Card connector. This power interface consists of two V_{CC} , two V_{pp} , and four ground terminals. Multiple V_{CC} and ground terminals minimize connector-terminal and line resistance. The two V_{pp} terminals were originally specified as separate signals, but are commonly tied together in the host to form a single node to minimize voltage losses. Card primary power is supplied through the V_{CC} terminals; flash-memory programming and erase voltage is supplied through the V_{DD} terminals.

designing for voltage regulation

The current PCMCIA specification for output-voltage regulation ($V_{O(reg)}$) of the 5-V output is 5% (250 mV). In a typical PC power-system design, the power supply has an output-voltage regulation ($V_{PS(reg)}$) of 2% (100 mV). Also, a voltage drop from the power supply to the PC Card will result from resistive losses (V_{PCB}) in the PCB traces and the PCMCIA connector. A typical design would limit the total of these resistive losses to less than 1% (50 mV) of the output voltage. Therefore, the allowable voltage drop (V_{DS}) for the TPS2205 would be the PCMCIA voltage regulation less the power supply regulation and less the PCB and connector resistive drops:

$$V_{DS} = V_{O(reg)} V_{PS(reg)} V_{PCB}$$

Typically, this would leave 100 mV for the allowable voltage drop across the TPS2205. The voltage drop is the output current multiplied by the switch resistance of the TPS2205. Therefore, the maximum output current that can be delivered to the PC Card in regulation is the allowable voltage drop across the TPS2205 divided by the output switch resistance.

$$I_{O}max = \frac{V_{DS}}{r_{DS(on)}}$$

The xVCC outputs have been designed to deliver 700 mA at 5 V within regulation over the operating temperature range. Current proposals for the PCMCIA specifications are to limit the power dissipated in the PCMCIA slot to 3 W. With an input voltage of 5 V, 700 mA continuous is the maximum current that can be delivered to the PC Card. The TPS2205 is capable of delivering up to 1 A continuously, but during worst-case conditions the output may not be within regulation. This is generally acceptable because the majority of PC Cards require less than 700 mA continuous. Some cards require higher peak currents (disk drives during initial platter spin-up), but it is generally acceptable for small voltage sags to occur during these peak currents.

The xVCC outputs have been designed to deliver 1 A continuously at 3.3 V within regulation over the operating temperature range. The PCMCIA specification for output voltage regulation of the 3.3-V output is 300 mV. Using the voltage drop percentages (2%) for power supply regulation and PCB resistive loss (1%), the allowable voltage drop for the 3.3 V switch is 200 mV.

The xVPP outputs have been designed to deliver 150 mA continuously at 12 V.



APPLICATION INFORMATION

overcurrent and over-temperature protection

PC Cards are inherently subject to damage that can result from mishandling. Host systems require protection against short-circuited cards that could lead to power supply or PCB-trace damage. Even systems sufficiently robust to withstand a short circuit would still undergo rapid battery discharge into the damaged PC Card, resulting in the rather sudden and unacceptable loss of system power. Most hosts include fuses for protection. The reliability of fused systems is poor, as blown fuses require troubleshooting and repair, usually by the manufacturer.

The TPS2205 takes a two-pronged approach to overcurrent protection. First, instead of fuses, sense FETs monitor each of the power outputs. Excessive current generates an error signal that linearly limits the output current, preventing host damage or failure. Sense FETs, unlike sense resistors or polyfuses, have an advantage in that they do not add to the series resistance of the switch and thus produce no additional voltage losses. Second, when an overcurrent condition is detected, the TPS2205 asserts a signal at OC that can be monitored by the microprocessor to initiate diagnostics and/or send the user a warning message. In the event that an overcurrent condition persists, causing the IC to exceed its maximum junction temperature, thermal-protection circuitry activates, shutting down all power outputs until the device cools to within a safe operating region.

12-V supply not required

Most PC Card switches use the externally supplied 12-V V_{pp} power for switch-gate drive and other chip functions, which requires that power be present at all times. The TPS2205 offers considerable power savings by using an internal charge pump to generate the required higher voltages from the 5-V or 3.3-V input; therefore, the external 12-V supply can be disabled except when needed for flash-memory functions, thereby extending battery lifetime. Do not ground the 12-V inputs when the 12-V input is not used. Additional power savings are realized by the TPS2205 during a software shutdown in which quiescent current drops to a maximum of 1 μ A.

backward compatibility and 3.3-V low-voltage mode

The TPS2205 is backward compatible with the TPS2201, with the following considerations. Pin 25 (V_{DD} on TPS2201) is a no connect because bias current is derived from either the 3.3-V input pin or the 5-V input pin. Also, the TPS2205 does not have the APWR_GOOD or BPWR_GOOD VPP reporting outputs. These are left as no connects.

The TPS2205 operates in 3.3-V low-voltage mode when 3.3 V is the only available input voltage ($V_{I(5V)}$ =0). This allows host and PC Cards to be operated in low-power 3.3-V-only modes such as sleep modes or pager modes. Note that in this operation mode, the TPS2205 derives its bias current from the 3.3-V input pin and only 3.3 V can be delivered to the PC Card. The 3.3-V switch resistance will be increased, but the added switch resistance should not be critical, because only a small amount of current is delivered in this mode. If 6% (198 mV) is allowed for the 3.3-V switch voltage drop, a 500 m Ω switch could deliver over 350 mA to the PC Card.

voltage transitioning requirement

PC Cards, like portables, are migrating from 5 V to 3.3 V to minimize power consumption, optimize board space, and increase logic speeds. The TPS2205 is designed to meet all combinations of power delivery as currently defined in the PCMCIA standard. The latest protocol accommodates mixed 3.3-V/5-V systems by first powering the card with 5 V, then polling it to determine its 3.3-V compatibility. The PCMCIA specification requires that the capacitors on 3.3-V-compatible cards be discharged to below 0.8 V before applying 3.3-V power. This ensures that sensitive 3.3-V circuitry is not subjected to any residual 5-V charge and functions as a power reset. The TPS2205 offers a selectable V_{CC} and V_{pp} ground state, in accordance with PCMCIA 3.3-V/5-V switching specifications, to fully discharge the card capacitors while switching between V_{CC} voltages.



APPLICATION INFORMATION

output ground switches

Several PCMCIA power-distribution switches on the market do not have an active-grounding FET switch. These devices do not meet the PC Card specification requiring a discharge of V_{CC} within 100 ms. PC Card resistance can not be relied on to provide a discharge path for voltages stored on PC Card capacitance because of possible high-impedance isolation by power-management schemes. A method commonly shown to alleviate this problem is to add to the switch output an external 100-k Ω resistor in parallel with the PC Card. Considering that this is the only discharge path to ground, a timing analysis shows that the RC time constant delays the required discharge time to more than 2 seconds. The only way to ensure timing compatibility with PC Card standards is to use a power-distribution switch that has an internal ground switch, like that of the TPS22xx family, or add an external ground FET to each of the output lines with the control logic necessary to select it.

In summary, the TPS2205 is a complete single-chip dual-slot PC Card power interface. It meets all currently defined PCMCIA specifications for power delivery in 5-V, 3.3-V, and mixed systems, and offers a serial control interface. The TPS2205 offers functionality, power savings, overcurrent and thermal protection, and fault reporting in one 30-pin SSOP surface-mount package, for maximum value added to new portable designs.

power supply considerations

The TPS2205 has multiple pins for each of its 3.3-V, 5-V, and 12-V power inputs and for the switched V_{CC} outputs. Any individual pin can conduct the rated input or output current. Unless all pins are connected in parallel, the series resistance is significantly higher than that specified, resulting in increased voltage drops and lost power. Both 12-V inputs must be connected for proper V_{pp} switching; it is recommended that all input and output power pins be paralleled for optimum operation.

Although the TPS2205 is fairly immune to power input fluctuations and noise, it is generally considered good design practice to bypass power supplies, typically with a 1- μ F electrolytic or tantalum capacitor paralleled by a 0.047- μ F to 0.1- μ F ceramic capacitor. It is strongly recommended that the switched V_{CC} and V_{pp} outputs be bypassed with a 0.1- μ F or larger capacitor; doing so improves the immunity of the TPS2205 to electrostatic discharge (ESD). Care should be taken to minimize the inductance of PCB traces between the TPS2205 and the load. High switching currents can produce large negative-voltage transients, which forward biases substrate diodes, resulting in unpredictable performance. Similary, no pin should be taken below –0.3 V.

overcurrent and thermal protection

The TPS2205 uses sense FETs to check for overcurrent conditions in each of the V_{CC} and V_{pp} outputs. Unlike sense resistors or polyfuses, these FETs do not add to the series resistance of the switch; therefore, voltage and power losses are reduced. Overcurrent sensing is applied to each output separately. When an overcurrent condition is detected, only the power output affected is limited; all other power outputs continue to function normally. The \overline{OC} indicator, normally a logic high, is a logic low when any overcurrent condition is detected, providing for initiation of system diagnostics and/or sending a warning message to the user.

During power up, the TPS2205 controls the rise time of the V_{CC} and V_{pp} outputs and limits the current into a faulty card or connector. If a short circuit is applied after power is established (e.g., hot insertion of a bad card), current is initially limited only by the impedance between the short and the power supply. In extreme cases, as much as 10 A to 15 A may flow into the short before the current limiting of the TPS2205 engages. If the V_{CC} or V_{pp} outputs are driven below ground, the TPS2205 may latch nondestructively in an off state. Cycling power will reestablish normal operation.

Overcurrent limiting for the V_{CC} outputs is designed to activate if powered up into a short in the range of 1 A to 2.2 A, typically at about 1.6 A. The V_{pp} outputs limit from 120 mA to 400 mA, typically around 280 mA. The protection circuitry acts by linearly limiting the current passing through the switch rather than initiating a full shutdown of the supply. Shutdown occurs only during thermal limiting.



APPLICATION INFORMATION

overcurrent and thermal protection (continued)

Thermal limiting prevents destruction of the IC from overheating if the package power-dissipation ratings are exceeded. Thermal limiting disables all power outputs (both A and B slots) until the device has cooled.

calculating junction temperature

The switch resistance, $r_{DS(on)}$, is dependent on the junction temperature, T_J , of the die. The junction temperature is dependent on both $r_{DS(on)}$ and the current through the switch. To calculate T_J , first find $r_{DS(on)}$ from Figures 20, 21, 22, and 23 using an initial temperature estimate about 50°C above ambient. Then calculate the power dissipation for each switch, using the formula:

$$P_D = r_{DS(on)} \times I^2$$

Next, sum the power dissipation and calculate the junction temperature:

$$T_{J} = (\Sigma P_{D} \times R_{\theta JA}) + T_{A}, R_{\theta JA} = 108^{\circ}C/W$$

Compare the calculated junction temperature with the initial temperature estimate. If the temperatures are not within a few degrees of each other, recalculate using the calculated temperature as the initial estimate.

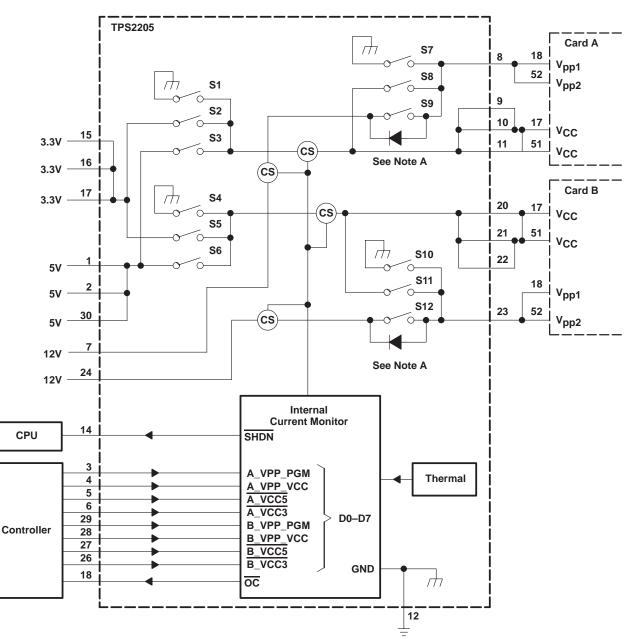
logic input and outputs

The TPS2205 was designed to be compatible with most popular PCMCIA controllers and current PCMCIA and JEIDA standards. However, some controllers require slightly counterintuitive connections to achieve desired output states. The TPS2205 control logic inputs A_VCC3 , A_VCC5 , B_VCC3 and B_VCC5 are defined active low (see Figure 31 and control-logic table). As such, they are directly compatible with the logic outputs of the Cirrus Logic CL-PD6720 controller.

The shutdown input (SHDN) of the TPS2205, when held at a logic low, places all V_{CC} and V_{pp} outputs in a high-impedance state and reduces chip quiescent current to 1 μ A to conserve battery power.

An overcurrent output (\overline{OC}) is provided to indicate an overcurrent condition in any of the V_{CC} or V_{pp} supplies (see discussion above).





APPLICATION INFORMATION

NOTE A: MOSFET switches S9 and S12 have a back-gate diode from the source to the drain. Unused switch inputs ;should never be grounded.

Figure 31. Internal Switching Matrix



APPLICATION INFORMATION

TPS2205 control logic

AVPP

CONTROL SIGNALS			INTERNAL SWITCH SETTINGS			OUTPUT
D8 SHDN	D0 A_VPP_PGM	D1 A_VPP_VCC	S7	S 8	S9	VAVPP
1	0	0	CLOSED	OPEN	OPEN	0 V
1	0	1	OPEN	CLOSED	OPEN	vcc†
1	1	0	OPEN	OPEN	CLOSED	VPP(12 V)
1	1	1	OPEN	OPEN	OPEN	Hi-Z
0	Х	X	OPEN	OPEN	OPEN	Hi-Z

BVPP

CONTROL SIGNALS			INTERNAL SWITCH SETTINGS			OUTPUT
D8 SHDN	D4 B_VPP_PGM	D5 B_VPP_VCC	S10	S11	S12	VBVPP
1	0	0	CLOSED	OPEN	OPEN	0 V
1	0	1	OPEN	CLOSED	OPEN	VCC‡
1	1	0	OPEN	OPEN	CLOSED	VPP(12 V)
1	1	1	OPEN	OPEN	OPEN	Hi-Z
0	Х	Х	OPEN	OPEN	OPEN	Hi-Z

AVCC

CONTROL SIGNALS			INTERNAL SWITCH SETTINGS			OUTPUT
D8 SHDN	D3 A_VCC3	D2 A_VCC5	S1	S2	S3	VAVCC
1	0	0	CLOSED	OPEN	OPEN	0 V
1	0	1	OPEN	CLOSED	OPEN	3.3 V
1	1	0	OPEN	OPEN	CLOSED	5 V
1	1	1	CLOSED	OPEN	OPEN	0 V
0	Х	Х	OPEN	OPEN	OPEN	Hi-Z

BVCC

CONTROL SIGNALS			INTERNAL SWITCH SETTINGS			OUTPUT
D8 SHDN	D6 B_VCC3	D7 B_VCC5	S4	S5	S6	VBVCC
1	0	0	CLOSED	OPEN	OPEN	0 V
1	0	1	OPEN	CLOSED	OPEN	3.3 V
1	1	0	OPEN	OPEN	CLOSED	5 V
1	1	1	CLOSED	OPEN	OPEN	0 V
0	Х	Х	OPEN	OPEN	OPEN	Hi-Z

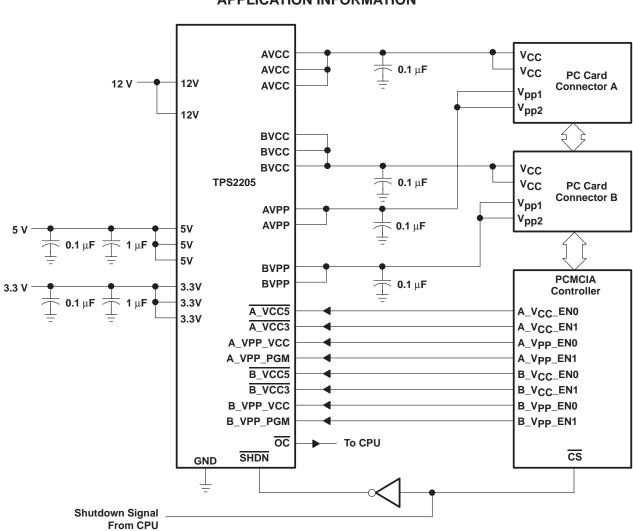
[†]Output depends on AVCC

[‡]Output depends on BVCC

ESD protection

All TPS2205 inputs and outputs incorporate ESD-protection circuitry designed to withstand a 2-kV human-body-model discharge as defined in MIL-STD-883C, Method 3015. The V_{CC} and V_{pp} outputs can be exposed to potentially higher discharges from the external environment through the PC Card connector. Bypassing the outputs with 0.1- μ F capacitors protects the devices from discharges up to 10 kV.





APPLICATION INFORMATION

Figure 32. Detailed Interconnections and Capacitor Recommendations

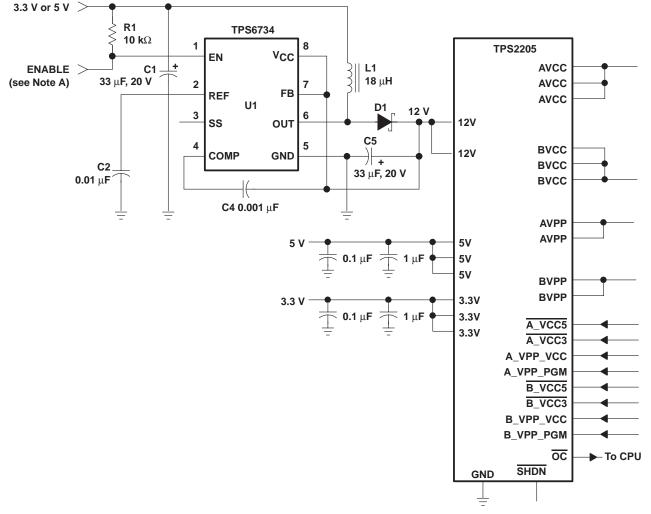


APPLICATION INFORMATION

12-V flash memory supply

The TPS6734 is a fixed 12-V output boost converter capable of delivering 120 mA from inputs as low as 2.7 V. The device is pin-for-pin compatible with the MAX734 regulator and offers the following advantages: lower supply current, wider operating input-voltage range, and higher output currents. As shown in Figure 1, the only external components required are: an inductor, a Schottky rectifier, an output filter capacitor, an input filter capacitor for loop compensation. The entire converter occupies less than 0.7 in² of PCB space when implemented with surface-mount components. An enable input is provided to shut the converter down and reduce the supply current to 3 μ A when 12 V is not needed.

The TPS6734 is a 170-kHz current-mode PWM (pulse-width modulation) controller with an n-channel MOSFET power switch. Gate drive for the switch is derived from the 12-V output after start-up to minimize the die area needed to realize the 0.7- Ω MOSFET and improve efficiency at input voltages below 5 V. Soft start is accomplished with the addition of one small capacitor. A 1.22-V reference (pin 2) is brought out for external use. For additional information, see the TPS6734 data sheet (SLVS127).



NOTE A: The enable terminal can be tied to a generall purpose I/O terminal on the PCMCIA controller or tied high.

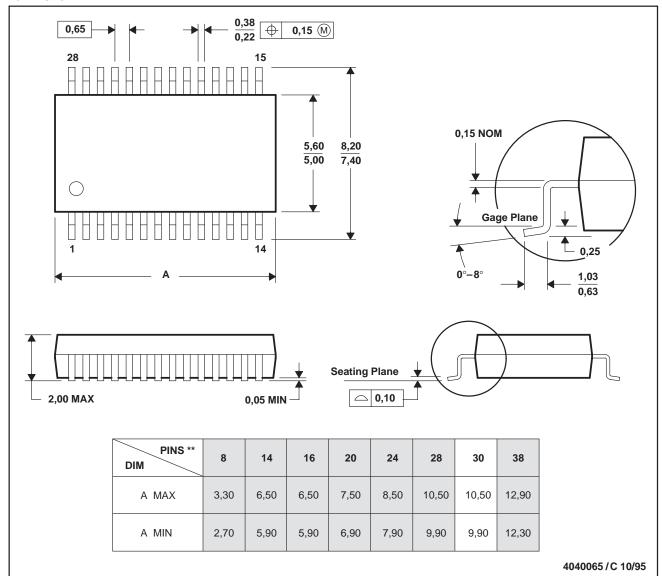
Figure 33. TPS2205 with TPS6734 12-V, 120-mA Supply



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE





NOTES: A. All linear dimensions are in millimeters.

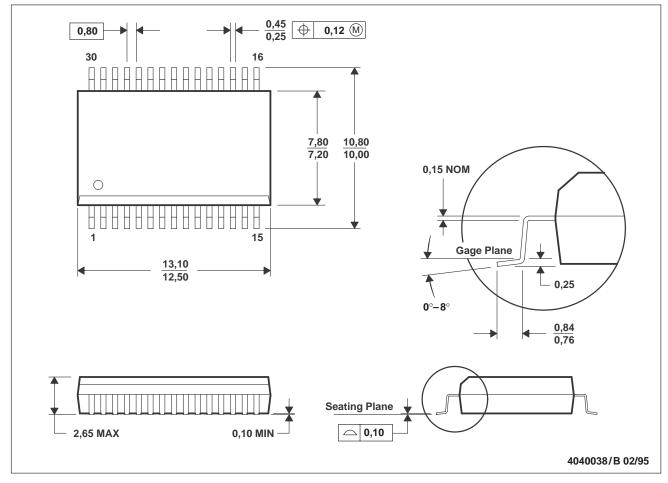
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



MECHANICAL DATA



PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

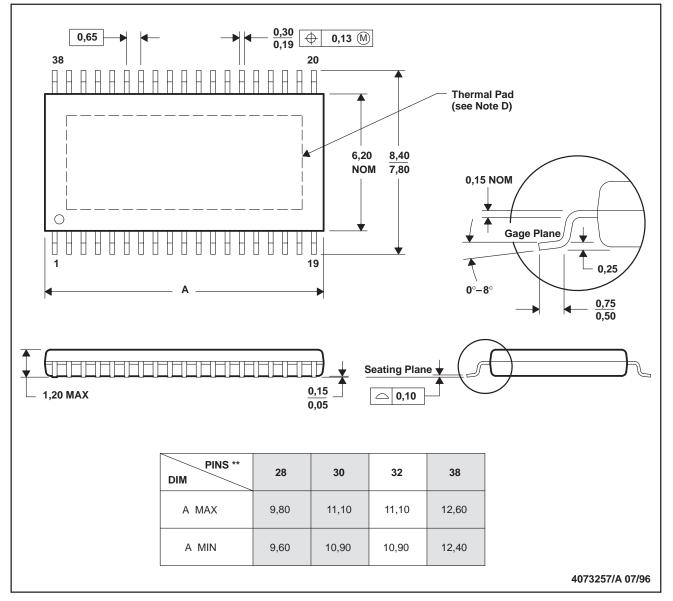
B. This drawing is subject to change without notice.



MECHANICAL DATA

PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

DAP (R-PDSO-G**) 38-PIN SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions include mold flash or protrusion.

D. The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane. This solderable pad is electrically and thermally connected to the backside of the die and possiblly selected leads. The maximum pad size on the printed circuit board should be equal to the package body size (2,0 mm).

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